#### May 1998

# National Semiconductor

### DS14C89A Quad CMOS Receiver

#### **General Description**

The DS14C89A, pin-for-pin compatible to the DS1489A/ MC1489A, ia a quad receiver designed to interface data terminal equipment (DTE) with data circuit-terminating equipment (DCE). These devices translate levels conforming to EIA-232E and CCITT V.28 standards to TTL/CMOS logic levels.

The device is fabricated in low threshold CMOS metal gate technology. The device provides very low power consumption compared to their bipolar equivalents: 900  $\mu$ A (DS14C89A) versus 26 mA (DS1489A).

The DS14C89A provides on chip noise filtering which eliminates the need for external response control filter capacitors.

### **Connection Diagram**

When replacing the DS1489A with the DS14C89A, the response control filter pins can be tied high, low, or not connected.

#### Features

- Meets EIA/TIA-232-E and CCITT V.28 Standards
- Failsafe Output High for Open Input
- LOW Power consumption
- On chip noise filter
- Available in SOIC Package

Input A V<sub>CC</sub> DS14C89A/DS14C89A1 <u>3</u>Input D NO <u>12</u>NC Output A 1 Input B Output D 10 Input C NC Output B NC GND Output C DS011106-1

Order Number DS14C89AN, DS14C89AM, See NS Package Number M14A, N14A DS14C89A Quad CMOS Receiver

#### Absolute Maximum Ratings (Note 1)

.

 $V_{CC}$ 

Input Voltage

N Package

M Package

Lead Temp.

Receiver Output Voltage

Junction Temperature

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

 $\begin{array}{ll} \mbox{(Soldering 4 seconds)} & +260\mbox{`C} \\ \mbox{Storage Temp. Range} & -65\mbox{`C to } +150\mbox{`C} \\ \mbox{ESD Rating} \geq 1.8\mbox{ kV}, \mbox{Typically} \geq 2\mbox{ kV} \\ \mbox{(HMB, 1.5 k}\Omega, 100\mbox{ pF)} \end{array}$ 

#### +6V -30V to +30V (V<sub>cc</sub>) +0.3V to GND-0.3V +0.3V to -30V

	Min	Max	Units
$V_{CC}$ (GND = 0V)	+4.5	+5.5	V
Operating Free Air Te	emp. (T <sub>A</sub> )		
DS14C89A	0	+75	°C

## Electrical Characteristics

Continuous Power Dissipation @ +25°C (Note 2)

Over recommended operating conditions, unless otherwise specified

Symbol	Parameter		Conditions	Min	Тур	Max	Units
V <sub>TH</sub>	Input High Threshold			1.3		2.7	V
V <sub>TL</sub>	Input Low Threshold			0.5		1.9	V
V <sub>HY</sub>	Typical Input Hysteresis				1.0		V
I <sub>IN</sub>	Input Current	V <sub>IN</sub> = +25V	$V_{\rm CC}$ = +4.5V to +5.5V	3.6		8.3	mA
		$V_{IN} = -25V$	-	-3.6		-8.3	mA
		$V_{IN} = +3V$	-	0.43		1.0	mA
		$V_{IN} = -3V$	-	-0.43		-1.0	mA
		V <sub>IN</sub> = +15V	V <sub>CC</sub> = 0V (Power-Off)	2.14		5.0	mA
		V <sub>IN</sub> = -15V	(Note 4)	-2.14		-5.0	mA
		$V_{IN} = +3V$	-	0.43		1.0	mA
		$V_{IN} = -3V$	-	-0.43		-1.0	mA
V <sub>OH</sub> Output High Voltage	V <sub>IN</sub> = V <sub>TL</sub> (min)	I <sub>OUT</sub> = -3.2 mA	2.8	4.0		V	
			Ι <sub>ΟUT</sub> = -20μΑ	3.5	4.7		V
V <sub>OL</sub>	Output Low Voltage	$V_{IN} = V_{TH}$ (max) $I_{OUT} = +3.2$ mA			0.15	0.4	v
I <sub>cc</sub>	Supply Current	No Load, V <sub>IN</sub> = 2	2.7V or 0.5V		0.5	900	μA

+150°C

1513 mW

1063 mW

#### AC Electrical Characteristics (Note 3)

Over recommended operating conditions, unless otherwise specified, C<sub>1</sub> = 50 pF

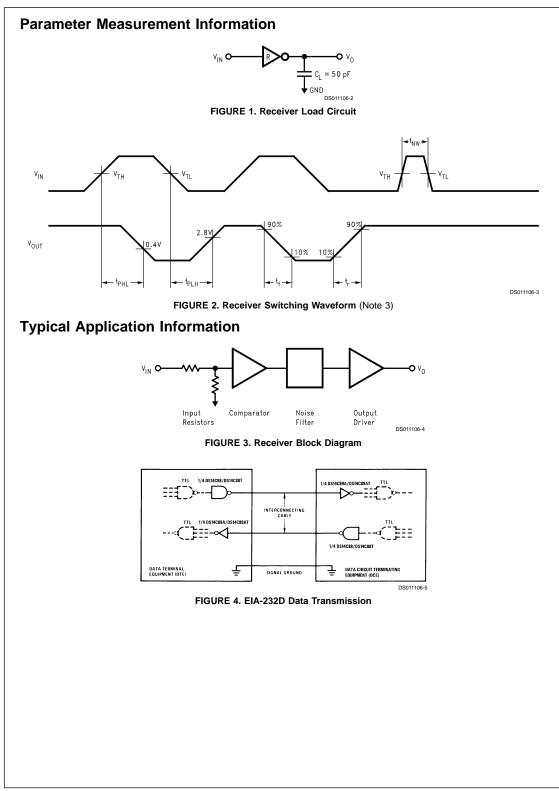
Symbol	Parameter	Conditions	Min	Тур	Max	Units
t <sub>PLH</sub>	Propagation Delay Low to High	Input Pulse Width ≥ 10 µs		3.5	6.5	μs
t <sub>PHL</sub>	Propagation Delay High to Low	Input Pulse Width ≥ 10 µs		3.2	6.5	μs
t <sub>sk</sub>	Typical Propagation Delay Skew			400		ns
t <sub>r</sub>	Output Rise TIme			40	300	ns
t <sub>f</sub>	Output Fall Time			40	300	ns
t <sub>nw</sub>	Pulse Width assumed to be Noise				1.0	μs

Note 1: "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The tables of "Electrical Characteristics" specify conditions for device operation.

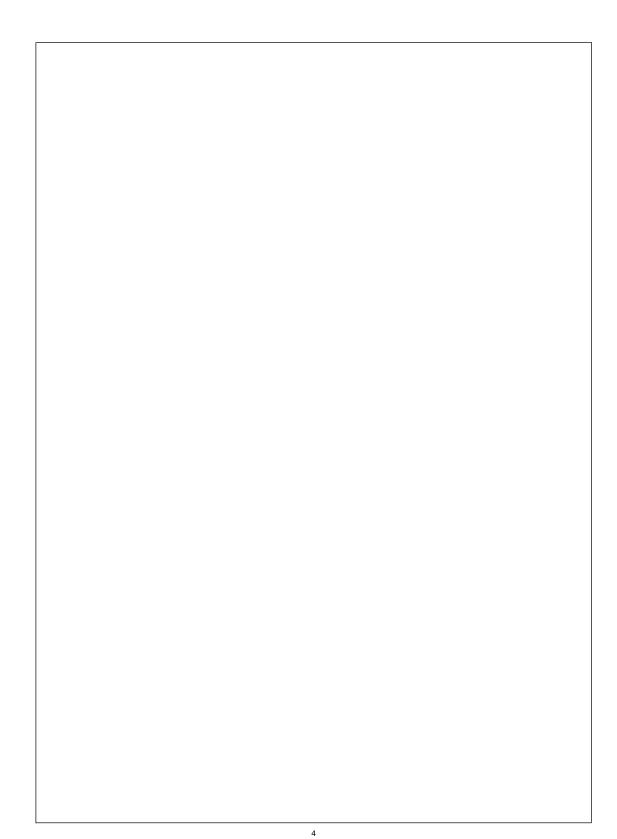
Note 2: Derate N Package 12.1 mW/°C, and M Package 8.5 mW/°C above +25°C.

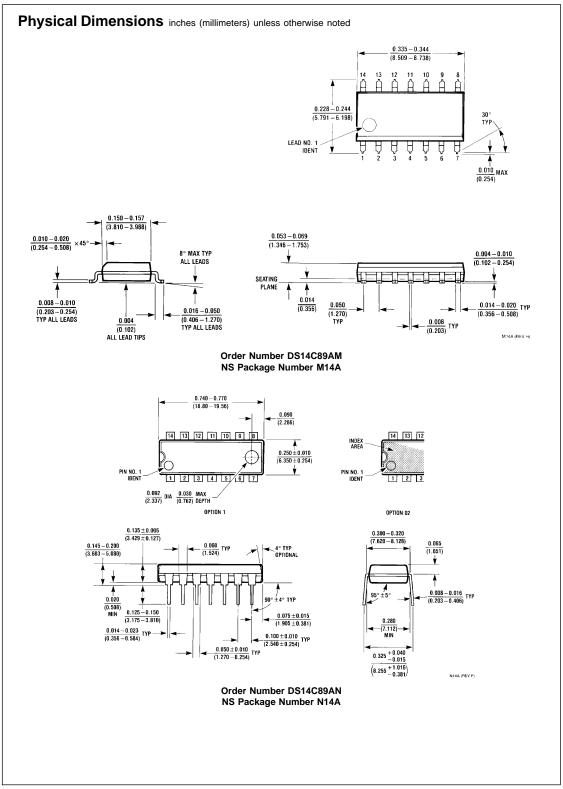
Note 3: AC input waveforms for test purposes:  $t_{\rm f}$  =  $t_{\rm f}$  = 200 ns, V\_{\rm IH} = +3V, V\_L = -3V, f = 20 KHz.

Note 4: Under the power-off supply conditions it is assumed that the power supply potential drops to zero (0V) and is replaced by a low impedance or short circuit to ground.



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